

## 4 Channel EMI Filter Array with ESD Protection

### **Features**

- Four channels of EMI filtering with ESD protection
- Greater than 25dB of attenuation from 800MHz to
- ±15kV ESD protection (IEC 61000-4-2, contact discharge)
- ±30kV ESD protection (MIL-STD-883, Method 3015, HBM)
- 8-lead TDFN package (2mm x 2mm), 0.5mm pitch
- Lead-free version available

### **Applications**

- I/O port protection for mobile handsets, notebook computers, PDAs etc.
- EMI filtering for data ports in cell phones, PDAs or notebook computers.
- EMI filtering for LCD and chip-to-chip data lines

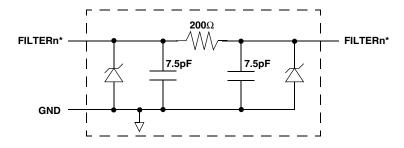
### **Product Description**

California Micro Devices's CM1407 is an EMI filter array with ESD protection, which integrates 4 pi filters (C-R-C). The CM1407 has component values of 7.5pF-200 $\Omega$ -7.5pF. The parts include ESD protection diodes on every pin, which provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The ESD diodes connected to the filter ports are designed and characterized to safely dissipate ESD strikes of ±15kV contact discharge, twice the specification requirement of the IEC 61000-4-2, Level 4 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the pins are protected for contact discharges at greater than ±30kV.

This device is particularly well-suited for portable electronics (e.g. mobile handsets, PDAs, notebook computers) because of its small package format and easyto-use pin assignments. In particular, the CM1407 is ideal for EMI filtering and protecting data lines from ESD in wireless handsets.

The CM1407 is available in a space-saving, low-profile, 8-lead, 2mm x 2mm TDFN package. It is fabricated with California Micro Devices' Centurion™ process and available with optional lead-free finishing.

#### **Electrical Schematic**

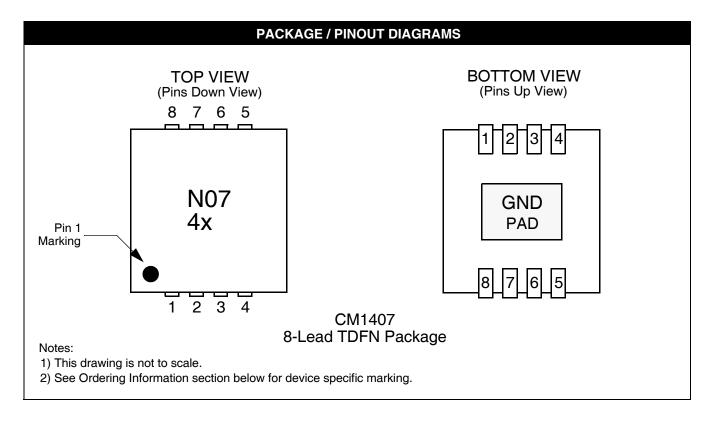


1 of 4 EMI Filtering + ESD Channels

1

<sup>\*</sup> See Package/Pinout Diagram for expanded pin information.





PIN DESCRIPTIONS						
PIN(s)	NAME	DESCRIPTION	PIN(s)	NAME	DESCRIPTION	
1	FILTER1	Filter Channel 1	5	FILTER4	Filter Channel 4	
2	FILTER2	Filter Channel 2	6	FILTER3	Filter Channel 3	
3	FILTER3	Filter Channel 3	7	FILTER2	Filter Channel 2	
4	FILTER4	Filter Channel 4	8	FILTER1	Filter Channel 1	
GND Pad	GND	Device Ground				

## **Ordering Information**

PART NUMBERING INFORMATION						
		Standard Finish Lead-free Finish				
		Ordering Part		Ordering Part		
Leads/Pins	Package	Number <sup>1</sup>	Part Marking	Number <sup>1</sup>	Part Marking	
8	TDFN-08	CM1407-04DF	N07 4F	CM1407-04DE	N07 4E	

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.



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## **Specifications**

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	RATING	UNITS			
Storage Temperature Range	-65 to +150	°C			
DC Power per Resistor	100	mW			
DC Package Power Rating	300	mW			

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature Range	-40 to +85	°C				

ELECTRICAL OPERATING CHARACTERISTICS (SEE NOTE 1)							
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
R	Resistance		160	200	240	Ω	
С	Capacitance	At 2.5V DC, 1MHz, 30mV AC	6	7.5	9	pF	
V <sub>DIODE</sub>	Diode Standoff Voltage	I <sub>DIODE</sub> = 10μA	5.5			V	
I <sub>LEAK</sub>	Diode Leakage Current (reverse bias)	V <sub>DIODE</sub> = 3.3V		100		nA	
V <sub>SIG</sub>	Signal Voltage Positive Clamp Negative Clamp	I <sub>LOAD</sub> = 10mA I <sub>LOAD</sub> = -10mA	5.6 -0.4	6.8 -0.8	9.0 -1.5	V	
V <sub>ESD</sub>	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2 Level 4	Notes 2,4 and 5	±30 ±15			kV kV	
V <sub>CL</sub>	Clamping Voltage during ESD Discharge MIL-STD-883 (Method 3015), 8kV Positive Transients Negative Transients	Notes 2,3,4 and 5		+12 -7		V	
f <sub>C</sub>	Cut-off Frequency $Z_{SOURCE}$ =50 $\Omega$ , $Z_{LOAD}$ =50 $\Omega$	R = 200Ω, C = 15pF		210		MHz	

Note 1:  $T_A=25$ °C unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: Clamping voltage is measured at the opposite side of the EMI filter to the ESD pin. For example, if ESD is applied to Pin 1, then clamping voltage is measured at Pin 8.

Note 4: Unused pins are left open

Note 5: These parameters are guaranteed by design and characterization.

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# Performance Information (cont'd)

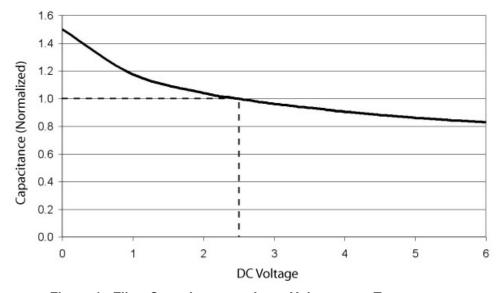


Figure 1. Filter Capacitance vs. Input Voltage over Temperature (normalized to capacitance at 2.5VDC and 25°C)



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### **Mechanical Details**

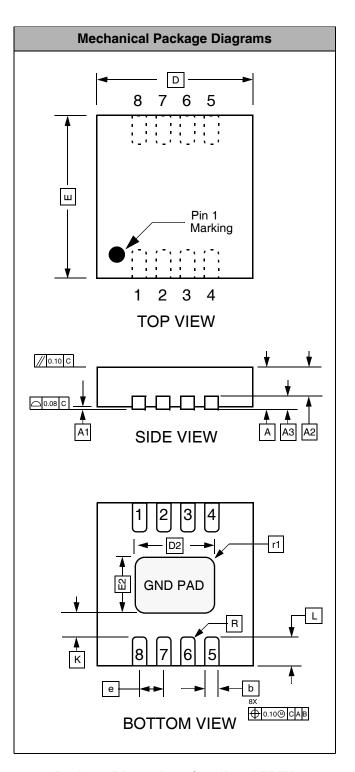
#### **TDFN-08 Mechanical Specifications**

Dimensions for the CM1407 device in an 8-lead TDFN package are presented below.

For complete information on the TDFN-08, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS							
Package	TDFN						
JEDEC No.	MO-229 (Var. VCCD-3) <sup>†</sup>						
Leads	8						
Dim.	Millimeters			Inches			
Dilli.	Min	Nom	Max	Min	Nom	Max	
Α	0.80	0.90	1.00	0.031	0.035	0.039	
A1	0.00	0.02	0.05	0.000	0.001	0.002	
A2	0.55	0.65	0.80	0.022	0.026	0.031	
А3		0.20			0.008		
b	0.18	0.25	0.30	0.007	0.010	0.012	
D		2.00			0.079		
D2	0.88	0.98	1.08	0.035	0.039	0.043	
E		2.00			0.079		
E2	0.46	0.56	0.66	0.018	0.022	0.026	
е		0.50			0.020		
K	0.20			0.008			
L	0.20	0.30	0.45	0.008	0.012	0.018	
R		0.075			0.003		
r1		0.075			0.003		
# per tube	NA						
# per tape and reel	3000 pieces						
	Controlling dimension: millimeters						

<sup>&</sup>lt;sup>†</sup>This package is compliant with JEDEC standard MO-229, variation VCCD-3 with exception of the "D2" and "E2" dimensions as called out in the table above and the "r1" dimension which is not specified in the MO-229 standard.



Package Dimensions for 8-Lead TDFN